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Ian T. Ferguson
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Introduction

The seventh conference on Solid State Lighting, part of the SPIE Annual Meeting, took place from 27–29 August 2007 in San Diego, California.

Contained in these proceedings are the 39 submitted papers of invited and contributing presenters in this conference. The topics covered by these papers range from semiconductor fabrication and characterization to solid state lighting systems development. They are representative of an unmistakable progression from academic research to industrial commercialization, fulfilling a promise that began with the first solid state lighting conference in 2001. At the same time, they also demonstrate that much exciting work remains to be done in the field.

The conference chairs would like to thank SPIE for hosting this meeting, as well as the program committee members, the authors, and the session chairs for making this meeting a technical success, and for providing valued and timely research on solid state lighting.

Ian T. Ferguson
Nadarajah Narendran
Tsunemasa Taguchi
Ian E. Ashdown